

High-speed dual differential comparator/sense amp**522****FEATURES**

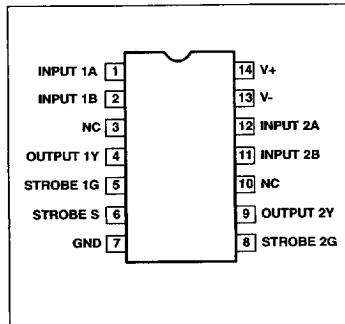
- 12 ns max guaranteed propagation delay
- 20 μ A max. Input bias current
- TTL compatible strobes and outputs
- Large common-mode input voltage range
- Operates from standard supply
- Open collector outputs

APPLICATIONS

- MOS memory sense amp
- A-to-D conversion
- High-speed line receiver

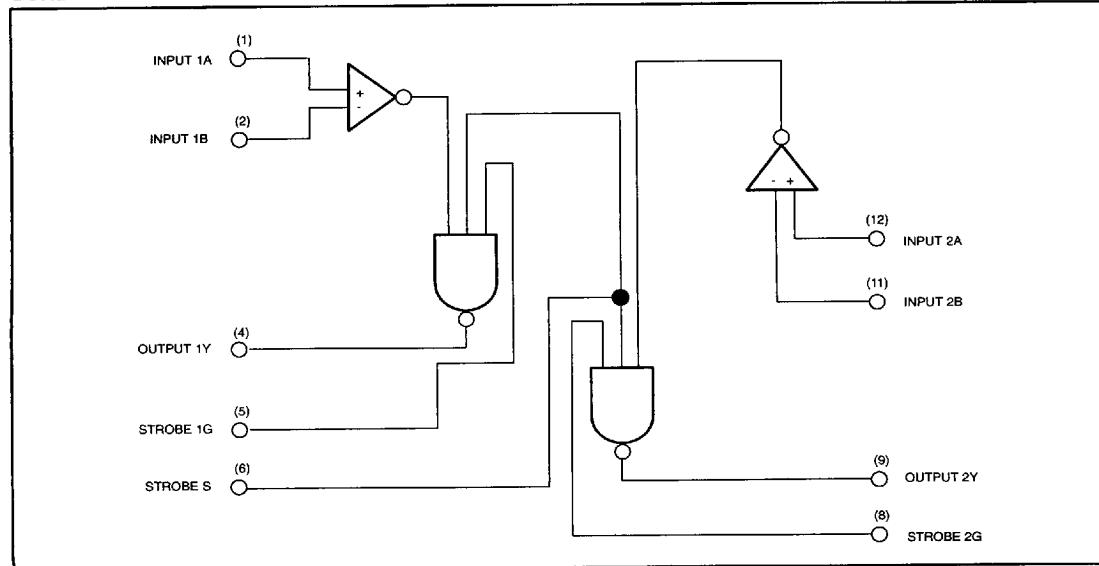
DESCRIPTION

The Dual Differential Comparator/Sense Amp is designed to convert line signals to TTL levels with a minimum addition propagation delay. Features include separate strobe output controls as well as a common output control.

PIN CONFIGURATION**ORDERING INFORMATION**

DESCRIPTION	ORDER CODE	PACKAGE DESIGNATOR*
14-Pin Ceramic DIP	522/BCA	GDIP1-T14
14-Pin Ceramic Flat Pack	522/BDA	GDFP1-F14

* MIL-STD 1835 or Appendix A of 1995 Military Data Handbook

EQUIVALENT SCHEMATIC

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High-speed dual differential comparator/sense amp

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ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING ¹			UNIT
V ₊	Supply voltage Positive		+7		V
V ₋	Supply voltage Negative		-7		V
V _{IDR}	Differential input voltage		±6		V
V _I	Input voltage Common mode Input voltage Strobe/gate		±5 +5.25		V
P _D	Power dissipation		600		mW
T _{STG}	Storage temperature range		-65 to +150		°C

DC ELECTRICAL CHARACTERISTICS

V₊ = +5V, V₋ = -5V, unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	T _{amb} = +25°C			T _{amb} = -55°C, +125°C			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V ₊ = +4.5V, V ₋ = -4.5V		6	7.5			15	mV
I _{IB}	Input bias current	V ₊ = +5.5V, V ₋ = -5.5V		7.5	20			40	μA
I _{IO}	Input offset current	V ₊ = +5.5V, V ₋ = -5.5V		1.0	5			12	μA
V _{ICR}	Common mode voltage range	V ₊ = +4.5V, V ₋ = -4.5V	±3			±3			V
Gate Characteristics									
V _{IL}	"0" input voltage	V ₊ = +4.5V, V ₋ = -4.5V			0.8			0.7	V
V _{IH}	"1" input voltage	V ₊ = +4.5V, V ₋ = -4.5V	2.0			2.0			V
I _{IH}	"1" input current	V ₊ = +5.5V, V ₋ = -5.5V, V _{IH} = 2.7V 1G or 2G strobe Common strobe S			50 100			50 100	μA μA
I _{IL}	"0" input current	V ₊ = +5.5V, V ₋ = -5.5V, V _{IL} = 0.5V 1G or 2G strobe Common strobe S			-2.0 -4.0			-2.0 -4.0	mA mA
V _{OL} V _{OOL}	Output voltage "0" State "0" State	V _{I(S)} = 2.0 V ₊ = +4.5V, V ₋ = -4.5V, I _{OL} = 10mA V ₊ = +4.5V, V ₋ = -4.5V, I _{OOL} = 20mA			0.5			0.5	V V
I _{OH}	Output leakage current	V ₊ = +4.5V, V ₋ = -4.5V, V _{OUT} = 5.5V			250			250	μA
Power Supply Requirements									
V ₊ V ₋	Supply voltage Positive Supply voltage Negative		4.5 4.5	5.0 5.0	5.5 5.5	4.5 4.5		5.5 5.5	V V
I _{CC+} I _{CC-}	Supply voltage Positive Supply voltage Negative	V ₊ = +5.5V, V ₋ = -5.5V I _{STROBE} = 0V		27 -15	35 -28			50 -28	mA mA

AC ELECTRICAL CHARACTERISTICS

T_A = 25°C, R_L = 280Ω, C_L = 15pF, V₊ = +5V, V₋ = -5V.

SYMBOL	PARAMETER	FROM INPUT	FROM OUTPUT	LIMITS			UNIT
				MIN	TYP	MAX	
Large Signal Switching Speed Propagation Delay							
t _{PLH(D)} t _{PHL(D)}	Low-to-High ² High-to-Low ²	Amp Amp	Output Output		10 8	15 12	ns ns
t _{PLH(S)} t _{PHL(S)}	Low-to-High ³ High-to-Low ³	Strobe Strobe	Output Output		6 5	13 9	ns ns

NOTES:

- Operation beyond limits in this table may impair the useful life of the device.
- Response time measured from 0V point of ±100mVp-p 10MHz square wave to the 1.5V point of the output.
- Response time measured from 1.5V prompt of input to 1.5V point of the output.

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